TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSV)

2SK3132

Chopper Regulator DC-DC Converter and Motor Drive Applications

• Low drain-source ON resistance : $R_{DS(ON)} = 0.07 \Omega$ (typ.)

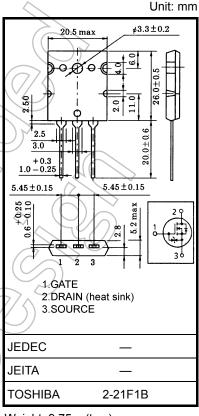
• High forward transfer admittance : $|Y_{fs}| = 33 \text{ S (typ.)}$

Low leakage current : I_{DSS} = 100 μA (max) (V_{DS} = 500 V)

• Enhancement mode : $V_{th} = 2.4 \text{ to } 3.4 \text{ V } (V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA})$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	500	V
Drain-gate voltage (R _{GS} = 20 kΩ)		V_{DGR}	500	y
Gate-source voltage		V _{GSS}	±30	> v
DCDrain current	DC (Note 1)	ID	50	Α
	Pulse (Note 1)	I _{DP}	200	Α
Drain power dissipation	n (Tc = 25°C)	P _D <	250	W
Single pulse avalanche energy (Note 2)		EAS	525	m)
Avalanche current		IAR	50	Α `
Repetitive avalanche energy (Note 3)		(EAR \	25	mJ
Channel temperature		Tch	150	- J.C
Storage temperature range		7/ T _{stg}	-55 to 150	√°C



Weight: 9.75 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics Sym	bol Max	Unit
Thermal resistance, channel to case Rth/c	ch-c) 0.5	°C / W
Thermal resistance, channel to ambient Rth (c	ch-a) 35.7	°C / W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 357 μ H, R_{G} = 25 Ω , I_{AR} = 50 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature.

This transistor is an electrostatic-sensitive device.

Please handle with caution.

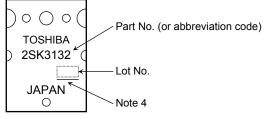
Electrical Characteristics (Ta = 25°C)

Charac	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	irrent	I _{GSS}	V _{GS} = ±25 V, V _{DS} = 0 V	_	_	±10	μΑ
Gate-source bre	eakdown voltage	V _(BR) GSS	$I_G = \pm 10 \ \mu A, \ V_{DS} = 0 \ V$	±30	_	_	V
Drain cut-off cur	rrent	I _{DSS}	V _{DS} = 500 V, V _{GS} = 0 V	7	_	100	μΑ
Drain-source br	eakdown voltage	V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	500		_	V
Gate threshold v	oltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	2.4) /_	3.4	V
Drain-source Ol	N resistance	R _{DS} (ON)	V _{GS} = 10 V, I _D = 25 A) 	0.07	0.095	Ω
Forward transfer	r admittance	Y _{fs}	V _{DS} = 10 V, I _D = 25 A	15	33	_	S
Input capacitano	e	C _{iss}			11000	_	
Reverse transfer	r capacitance	C _{rss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	2100	_	pF
Output capacitar	nce	Coss		_	4200	_	
Switching time	Rise time	tr	$V_{\rm GS} \stackrel{10V}{\underset{\rm C}{\longrightarrow}} \stackrel{I_{\rm D}=25{\rm A}}{\underset{\rm R_L=8\Omega}{\longrightarrow}}$	- (105) I	
	Turn-on time	t _{on}			160) —	
	Fall time	t _f	v _{DD} =200V		65	l	ns
	Turn-off time	t _{off}	Duty $\leq 1\%$, $t_{\mathbf{w}} = 10 \mu s$) –	245	l	
Total gate charg plus gate-drain)		Qg		_	280	_	
Gate-source cha	arge	Q _{gs}	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 50 \text{ A}$	_	150	_	nC
Gate-drain ("mil	ler") charge	Q _{gd}		_	130	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	IDR	<u> </u>	_	-	50	Α
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	200	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 25 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	I _{DR} = 50 A, V _{GS} = 0 V		600	_	ns
Reverse recovery charge	Q _{rr}	dl _{DR} / dt = 100 A / μs	-	12	_	μC

Marking

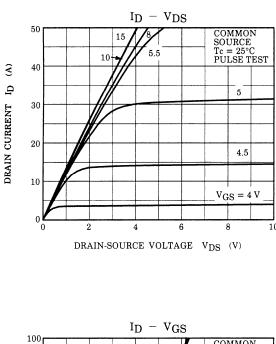


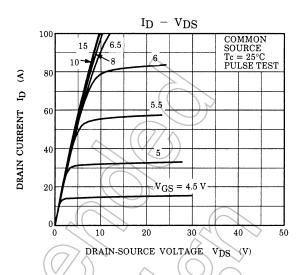
Note 4: A line under a Lot No. identifies the indication of product Labels.

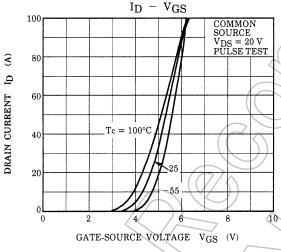
Not underlined: [[Pb]]/INCLUDES > MCV

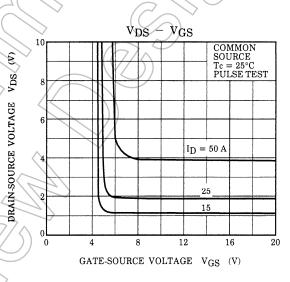
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

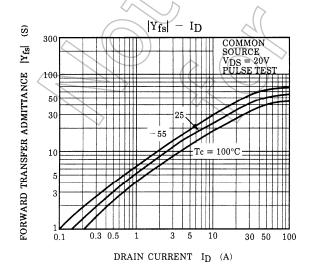
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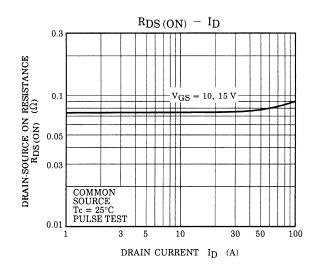




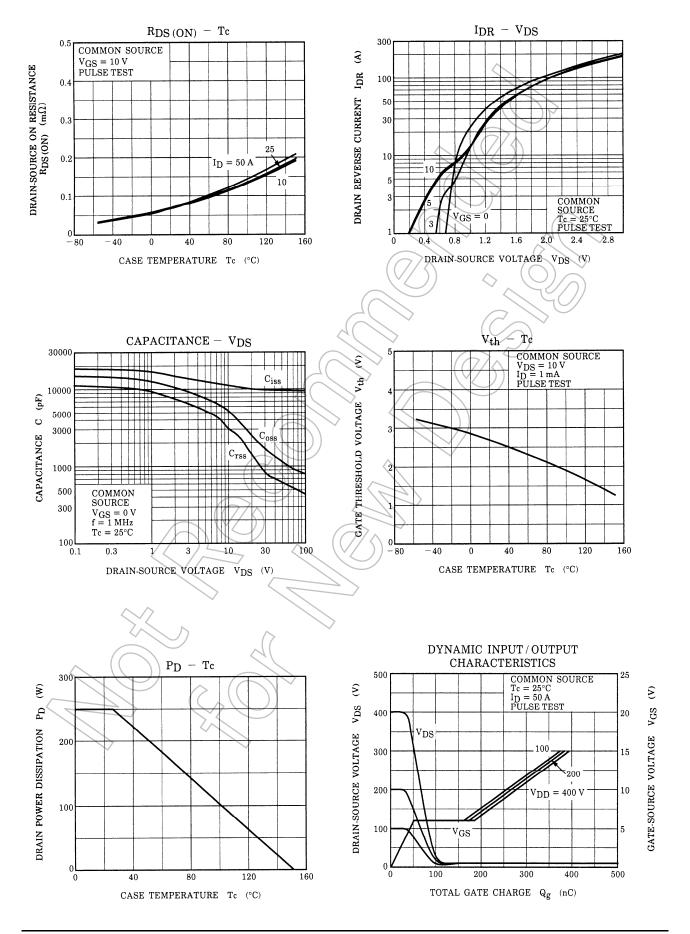


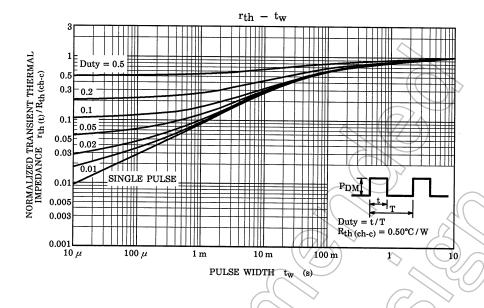


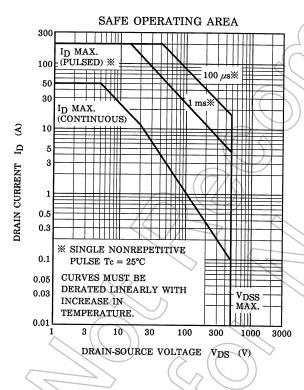


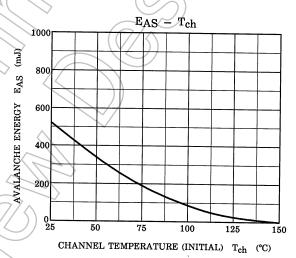


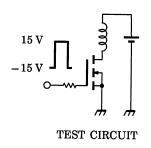
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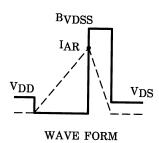












$$R_G$$
 = 25 Ω
 V_{DD} = 90 V, L = 357 μH

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^{2} \cdot \left(\frac{B_{VDSS}}{B_{VDSS} - V_{DD}} \right)$$

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